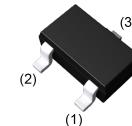


NPN 100mA 50V Digital Transistor (Bias Resistor Built-in Transistor)

Features

1) Built-In Biasing Resistors,
 $R_1 = 1\text{k}\Omega$, $R_2 = 10\text{k}\Omega$

SOT-23



2) Built-in bias resistors enable the configuration of
an inverter circuit without connecting external
input resistors (see inner circuit).

3) Only the on/off conditions need to be set
for operation, making the circuit design easy.

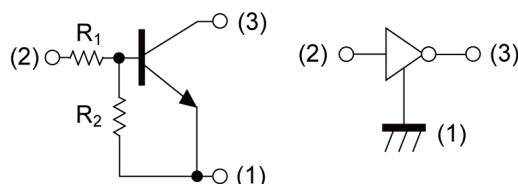
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Application

INVERTER, INTERFACE, DRIVER

Parameter	Value
V_{CC}	50V
$I_C(\text{MAX.})$	100mA
R_1	1.0k Ω
R_2	10k Ω

Inner circuit



(1) GND (EMITTER)
(2) IN (BASE)
(3) OUT (COLLECTOR)

Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Values	Unit
Supply voltage	V_{CC}	50	V
Input voltage	V_{IN}	-5 to 10	V
Output current	I_O	100	mA
Collector current	$I_{C(MAX)}^{*1}$	100	mA
Power dissipation	P_D^{*2}	200	mW
Junction temperature	T_j	150	°C
Range of storage temperature	T_{stg}	-55 to +150	°C

Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input voltage	$V_{I(off)}$	$V_{CC} = 5\text{V}, I_O = 100\mu\text{A}$	-	-	0.3	V
	$V_{I(on)}$	$V_O = 0.3\text{V}, I_O = 20\text{mA}$	3.0	-	-	
Output voltage	$V_{O(on)}$	$I_O = 10\text{mA}, I_I = 0.5\text{mA}$	-	100	300	mV
Input current	I_I	$V_I = 5\text{V}$	-	-	7.2	mA
Output current	$I_{O(off)}$	$V_{CC} = 50\text{V}, V_I = 0\text{V}$	-	-	500	nA
DC current gain	G_I	$V_O = 5\text{V}, I_O = 5\text{mA}$	33	-	-	-
Input resistance	R_I	-	0.7	1.0	1.3	kΩ
Resistance ratio	R_2/R_1	-	8	10	12	-
Transition frequency	f_T^{*1}	$V_{CE} = 10\text{V}, I_E = -5\text{mA}, f = 100\text{MHz}$	-	250	-	MHz

*1 Characteristics of built-in transistor

*2 Each terminal mounted on a reference land.

Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.1 Input voltage vs. output current (ON characteristics)

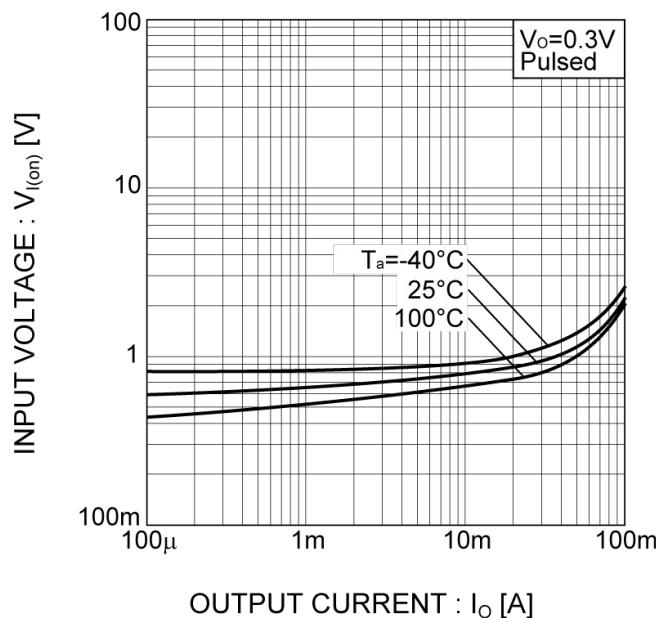


Fig.2 Output current vs. input voltage (OFF characteristics)

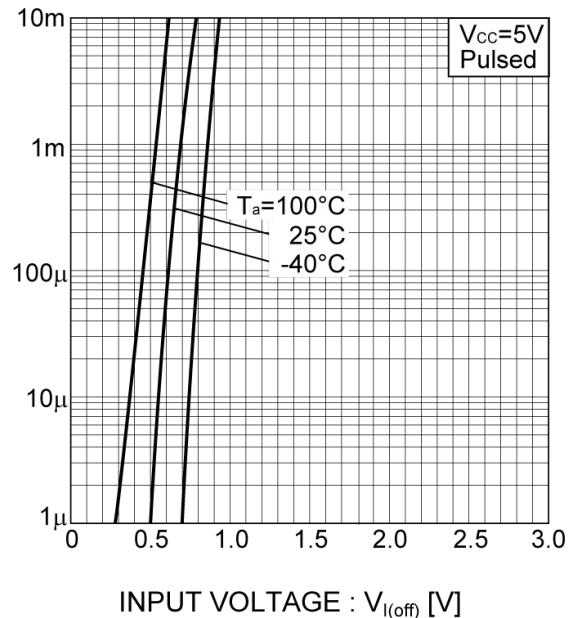


Fig.3 Output current vs. output voltage

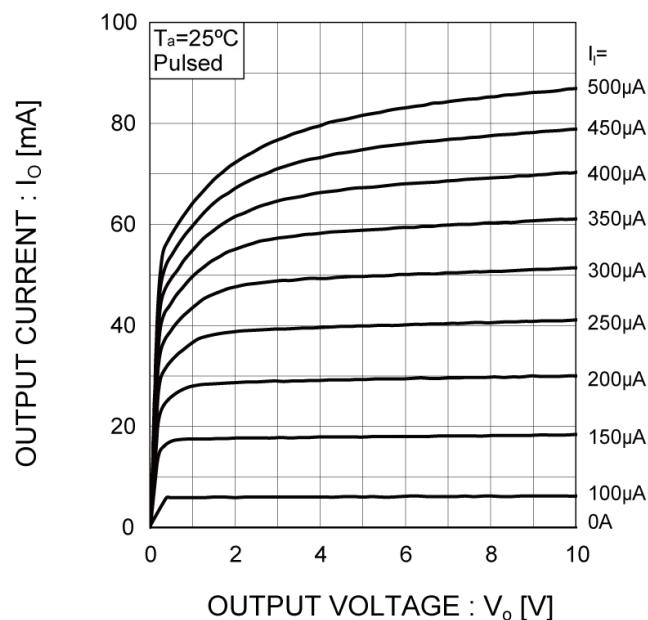
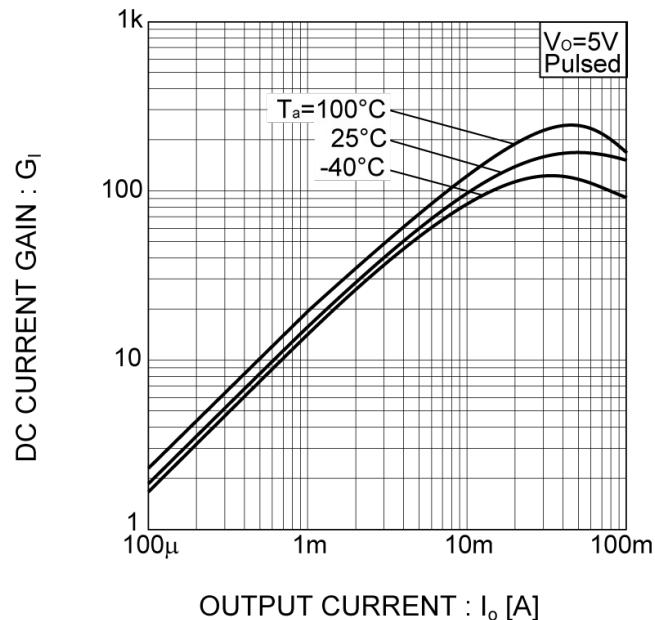
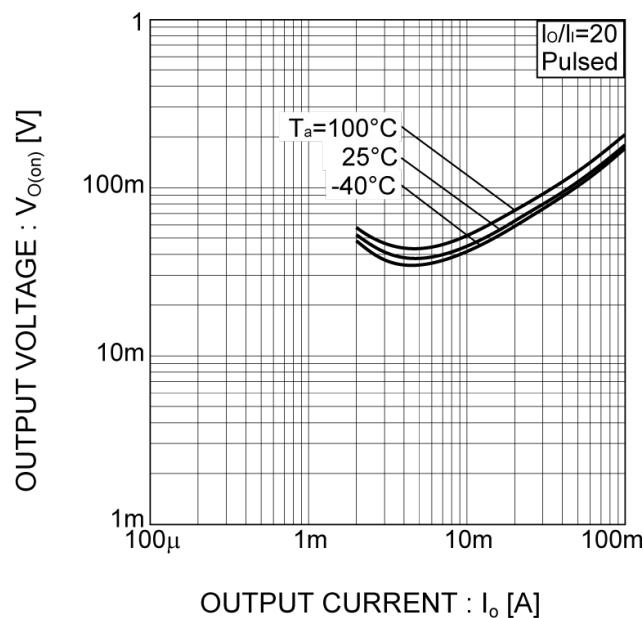


Fig.4 DC current gain vs. output current

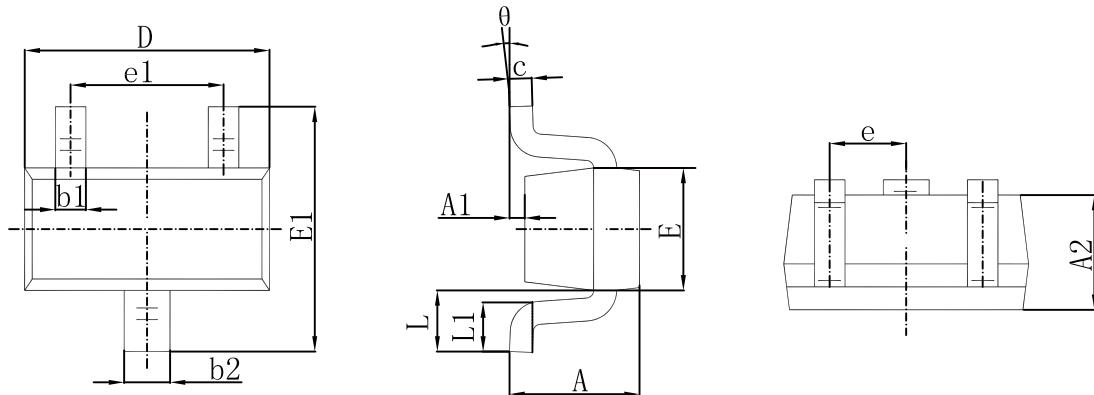


Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.5 Output voltage vs. output current

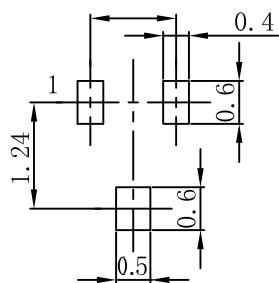


SOT-523 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-523 Suggested Pad Layout



Note:
 1. Controlling dimension:in millimeters.
 2.General tolerance: $\pm 0.05\text{mm}$.
 3.The pad layout is for reference purposes only.